



UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE
 United States Patent and Trademark Office
 Address: COMMISSIONER FOR PATENTS
 P.O. Box 1450
 Alexandria, Virginia 22313-1450
 www.uspto.gov



Bib Data Sheet

CONFIRMATION NO. 4282

SERIAL NUMBER 10/720,378	FILING DATE 11/25/2003 RULE	CLASS 257	GROUP ART UNIT 2814	ATTORNEY DOCKET NO. 492322001810
-----------------------------	---------------------------------------	--------------	------------------------	--

APPLICANTS

Nobuyuki Sekikawa, Ashikagai-shi, JAPAN;
 Masaaki Momen, Ojiya-shi, JAPAN;
 Wataru Andoh, Kamo-shi, JAPAN; Koichi Hirata, Sanjo-shi, JAPAN;

** CONTINUING DATA ***** *RCE* *SL*
 This application is a DIV of 09/925,628 08/10/2001 PAT 6,690,070

** FOREIGN APPLICATIONS ***** *YLS* *SL*
 JAPAN 2000-242617 08/10/2000

IF REQUIRED, FOREIGN FILING LICENSE GRANTED
 ** 03/11/2004

Foreign Priority claimed 35 USC 119 (a-d) conditions met Verified and Acknowledged	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance <i>SL (2/28/06)</i> Examiner's Signature Initials	STATE OR COUNTRY JAPAN	SHEETS DRAWING 3	TOTAL CLAIMS 6	INDEPENDENT CLAIMS 2
--	---	------------------------------	------------------------	----------------------	----------------------------

ADDRESS
 Barry E. Bretschneider
 Morrison & Foerster LLP
 Suite 300
 20001650 Tysons Boulevard
 McLean, VA
 22102

TITLE
 Method of manufacturing insulated gate semiconductor device

FILING FEE	FEES: Authority has been given in Paper	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of
------------	---	---

RECEIVED 770	No. _____ to charge/credit DEPOSIT ACCOUNT	time)
	No. _____ for following:	<input type="checkbox"/> 1.18 Fees (Issue)
		<input type="checkbox"/> Other _____
		<input type="checkbox"/> Credit